

1.Features

- Bidirectional ESD protection of oneline
- Very low diode capacitance: $C_d=11\text{pF}$
- Max. peak pulse power: $P_{pp}=45\text{W}$
- Low clamping voltage: $V_{CL}=12.5\text{V}$
- Ultra low leakage current: $I_{RM}<1\text{nA}$
- ESD protection up to 30kV
- IEC61000-4-2; level4 (ESD)
- IEC61000-4-5 (surge); $I_{PP}=4.8\text{A}$
- AEC-Q101 qualified

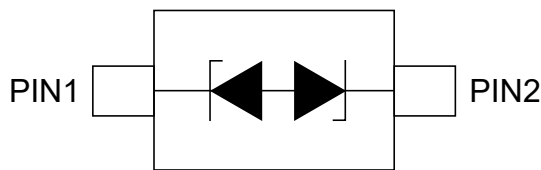
3.Mechanical Data

- SOD-882 package
- Molding compound flammability rating: UL 94V-0

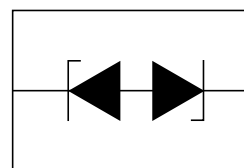
2.Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- Subscriber Identity Module(SIM) card protection
- Communication systems
- Portable electronics
- 10/100Mbit/sEthernet
- FireWire

4.Pinning information



SOD-323/523



SOD-882



5. Quick reference data

$T_{amb}=25^{\circ}\text{C}$ unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Units
reverse standoff voltage	V_{RWM}				5	V
diode capacitance	C_d	$V_R=0\text{V}$, $f=1\text{MHz}$		11	13	pF

6. Ordering information

Type number	Name	Description	Version
PESD5V0V1BA	SC-76	plastic surface-mounted package; 2 leads	SOD323
PESD5V0V1BB	SC-79	plastic surface-mounted package; 2 leads	SOD523
PESD5V0V1BL		leadless ultra small plastic package; 2 terminals; body 1.0 ? 0.6 ? 0.5 mm	SOD882

7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Per diode						
peak pulse power	P_{PP}	$t_p=8/20\mu\text{s}$ ①			45	W
peak pulse current	I_{PP}	$t_p=8/20\mu\text{s}$ ①			4.8	A
Per device						
junction temperature	T_J				150	$^{\circ}\text{C}$
ambient temperature	T_{amb}		-55		150	$^{\circ}\text{C}$
storage temperature	T_{STG}		-65		150	$^{\circ}\text{C}$

Notes:

① Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.



8.ESD maximum ratings

T_{amb}=25 °C unless otherwise specified

Parameter	Symbol	Conditions	Min	Typ	Max	Units
electrostatic discharge voltage	V _{ESD}	IEC 61000-4-2 (contact discharge) ①			30	kV
		machine model			2	kV
		MIL-STD-883 (human body model)			16	kV

Notes:

① Device stressed with ten non-repetitive ESD pulses.

9.ESD standards compliance

Parameter	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV



10. Electrical Characteristic ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
reverse stand off voltage	V_{RWM}				5	V
reverse leakage current	I_{RM}	$V_{RWM}=5\text{V}$		<1	10	nA
breakdown voltage	V_{BR}	$I_R=5\text{mA}$	5.8	6.8	7.8	V
diode capacitance	C_d	$f=1\text{MHz}$, $V_R=0\text{V}$		11	13	pF
clamping voltage	V_{CL}	$I_{PP}=4.8\text{A}$ ①			12.5	V
dynamic resistance	r_{dyn}	$I_R=10\text{A}$ ②		0.2		Ω
differential resistance	r_{dif}	$I_R=5\text{mA}$			35	Ω

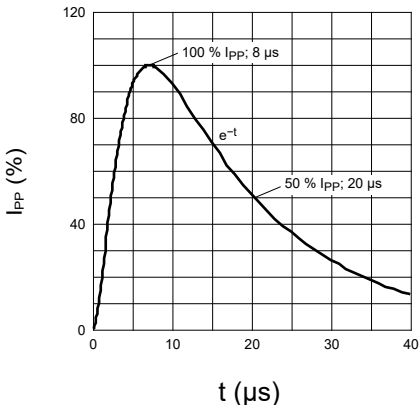
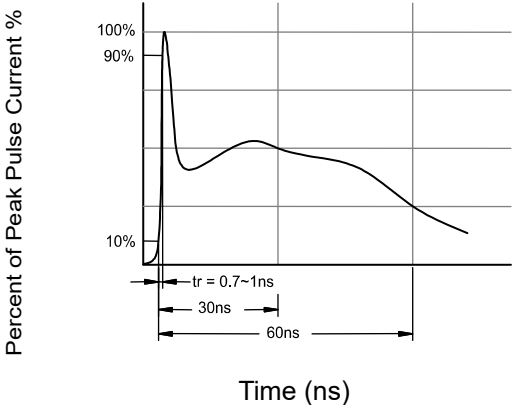
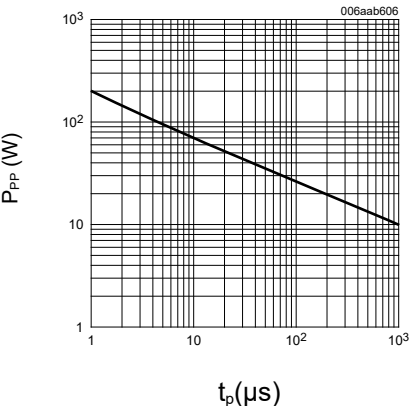
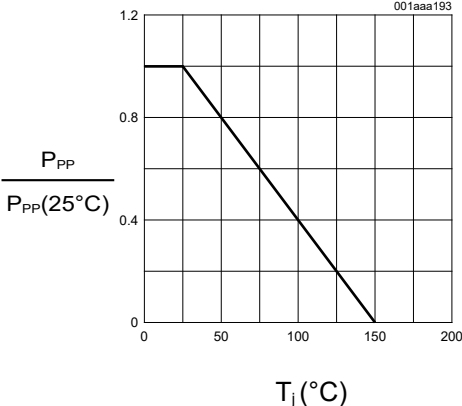
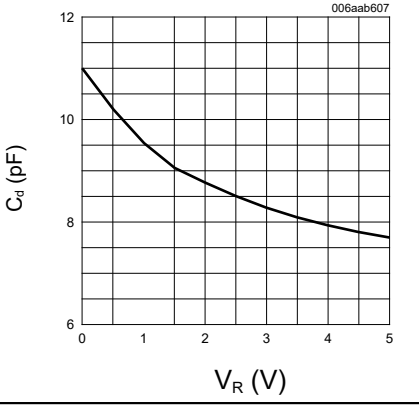
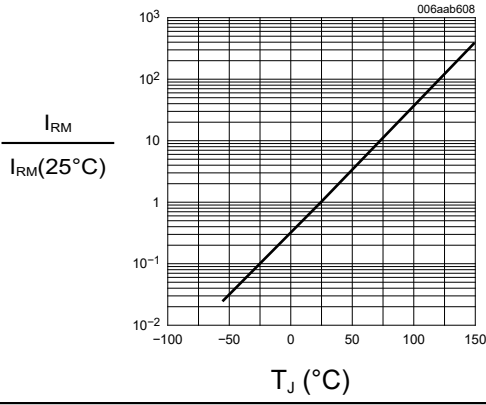
Notes:

① Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC 61000-4-5.

② Non-repetitive current pulse, Transmission Line Pulse (TLP) $t_p=100\text{ ns}$; square pulse; ANS/IESD STM5.1-2008.

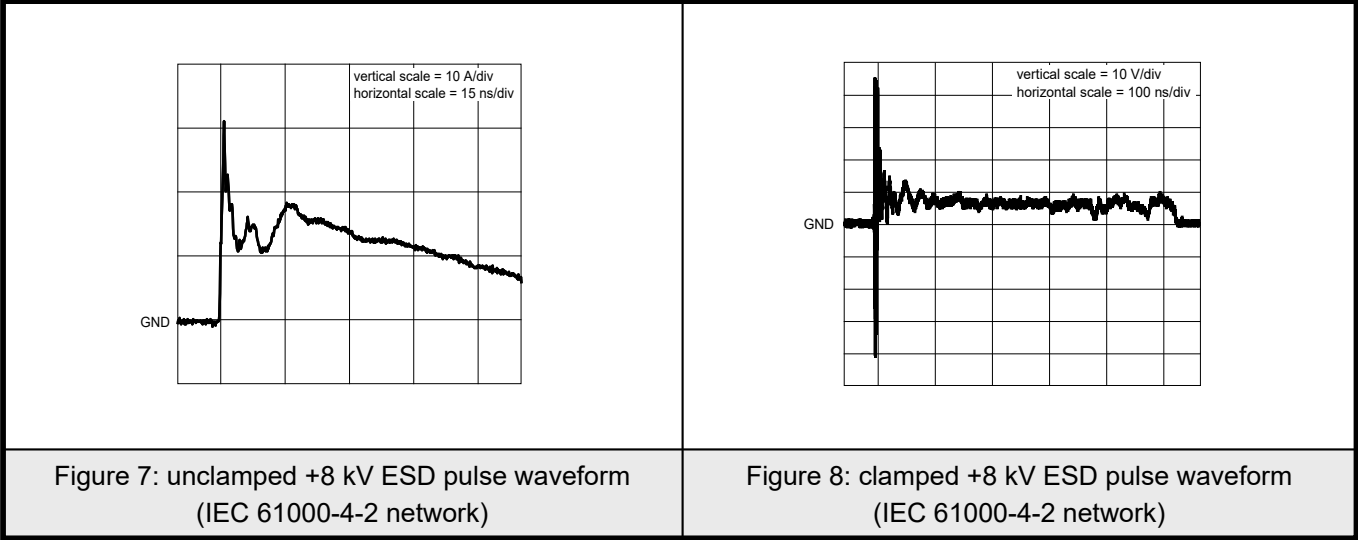


11.1Typical characteristic

	
Figure 1: 8/20µs pulse waveform according to IEC 61000-4-5	Figure 2: ESD pulse waveform according to IEC 61000-4-2
	
Figure 3: Peak pulse power as a function of exponential pulse duration; typical values	Figure 4: Relative variation of peak pulse power as a function of junction temperature; typical values
	
Figure 5: Diode capacitance as a function of reverse voltage; typical values	Figure 6: Relative variation of reverse leakage current as a function of junction temperature; typical values

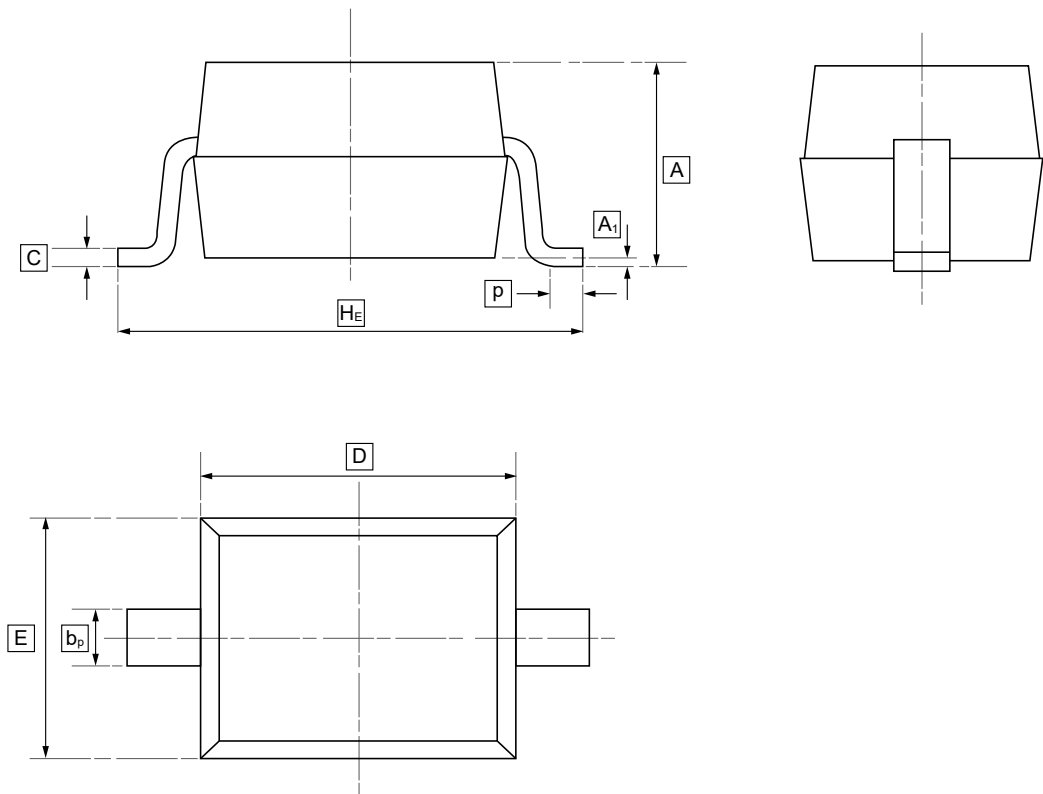


11.2Typical characteristic





12.1SOD-323 Package Outline Dimensions

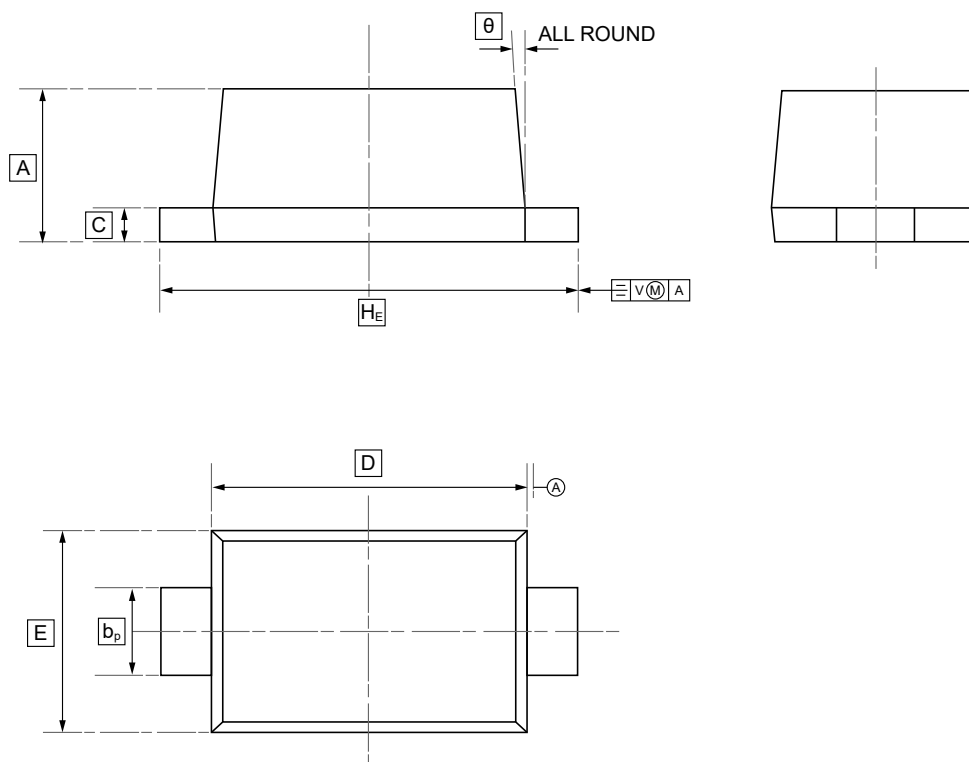


DIMENSIONS (mm are the original dimensions)

Symbol	A	b _p	C	D	E	H _E	A ₁	L _p
Min	0.90	0.25	0.10	1.60	1.15	2.30	0.01	0.20
Max	1.20	0.40	0.15	1.80	1.35	2.80	0.10	0.50



12.2.SOD-523 Package Outline Dimensions

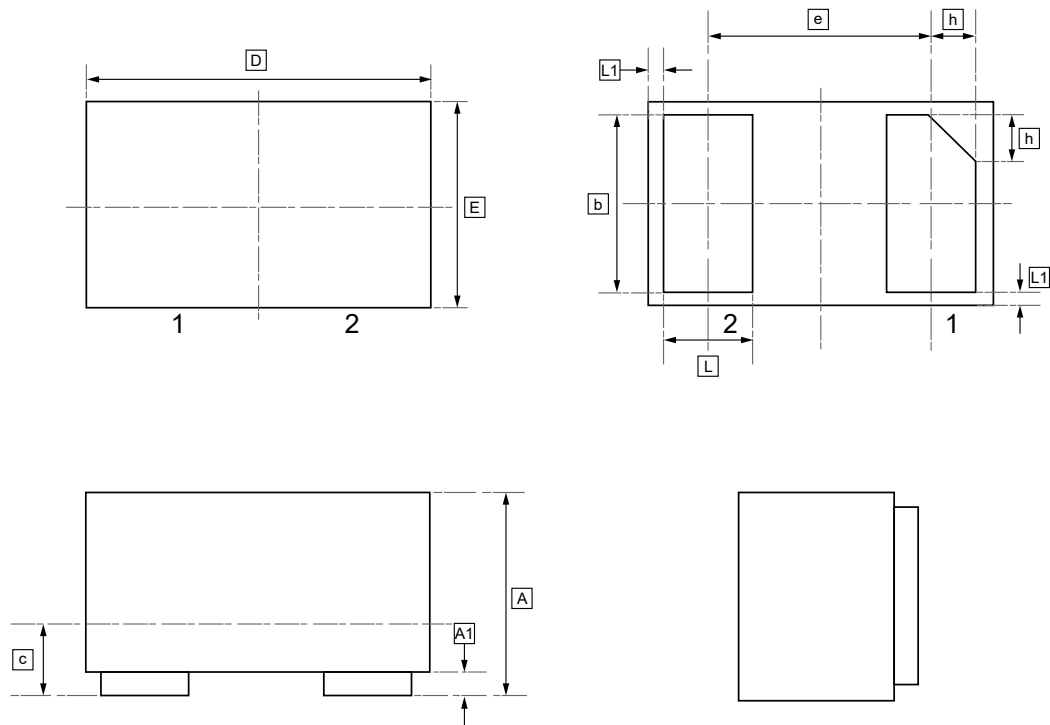


DIMENSIONS (mm are the original dimensions)

Symbol	A	b _p	C	D	E	H _E	θ
Min	0.58	0.3	0.100	1.15	0.75	1.5	5°
Max	0.68	0.4	0.135	1.25	0.85	1.7	



12.3.SOD-882 Package Outline Dimensions

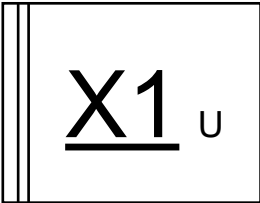


DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	b	c	D	e	E	L	L1	h
Min	0.45	0.00	0.45	0.12	0.95	0.65	0.55	0.20	0.05	0.07
Max	0.55	0.05	0.55	0.18	1.05	BSC	0.65	0.30	REF	0.17



13.Ordering information



Order Code	Marking	Package	Base QTY	Delivery Mode
UMW PESD5V0V1BA	1K	SOD-323	10000	Tape and reel
UMW PESD5V0V1BB	Z9	SOD-523	10000	Tape and reel
UMW PESD5V0V1BL	X1	SOD-882	10000	Tape and reel



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